Nch+Nch 20V 300mA Small Signal MOSFET

V_{DSS}	20V
R _{DS(on)} (Max.)	1.0Ω
I _D	±300mA
P _D	150mW

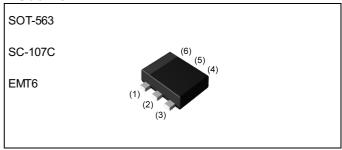
Features

- 1) The MOSFET elements are independent, eliminating mutual interference.
- 2) Mounting cost and area can be cut in half.
- 3) Low on-resistance.
- 4) Low voltage drive (1.8V) makes this device ideal

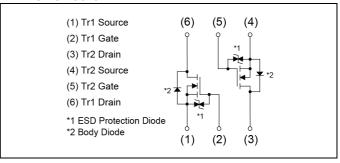
for portable equipment.

5) Pb-free lead plating; RoHS compliant.

Outline



Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	180
Туре	Tape width (mm)	8
-	Basic ordering unit (pcs)	8000
	Taping code	T2R
	Marking	K06

Application

Switching

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified) < Tr1 and Tr2>

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V_{DSS}	20	V
Continuous drain current		I _D	±300	mA
Pulsed drain current	I _{DP} *1	±600	mA	
Gate - Source voltage		V_{GSS}	±8	V
Power dissipation total elemen		D *2	150	\^/
		- P _D *2	120	mW
Junction temperature	T _j	150	°C	
Operating junction and storage temperature range		T _{stg}	-55 to +150	°C

●Thermal resistance

Davomotov	Cumphal	Values			1.1	
Parameter		Symbol	Min.	Тур.	Max.	Unit
Thermal registance investign, ambient	total	R _{thJA} *2	-	-	833	°C/W
Thermal resistance, junction - ambient	element		1	-	1042	C/VV

●Electrical characteristics (T_a = 25°C) <Tr1 and Tr2>

Davamatav	Curanh al	Conditions	Values			Linit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	20	-	-	V	
Breakdown voltage	ΔV _{(BR)DSS}	I _D = 1mA		29.0	_	mV/°C	
temperature coefficient	ΔT_{j}	referenced to 25°C	1	29.0	-	IIIV/ C	
Zero gate voltage drain current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0V		-	1	μА	
Gate - Source leakage current	I _{GSS}	$V_{DS} = 0V$, $V_{GS} = \pm 8V$	-	-	±10	μА	
Gate threshold voltage	V _{GS(th)}	V _{DS} = 10V, I _D = 1mA	0.3	-	1.0	V	
Gate threshold voltage	$\Delta V_{GS(th)}$	I _D = 1mA		1.6		m\//°C	
temperature coefficient	ΔT _j	referenced to 25°C	1.6		-	mV/°C	
		V _{GS} = 4.0V, I _D = 300mA	-	0.7	1.0		
Static drain - source on - state resistance	R _{DS(on)} *3	$V_{GS} = 2.5V, I_D = 300 \text{mA}$ - 0.8		8.0	1.2	Ω	
		V _{GS} = 1.8V, I _D = 300mA	-	1.0	1.4		
Forward Transfer Admittance	Y _{fs} *3	V _{DS} = 10V, I _D = 300mA	400	-	-	mS	

● Electrical characteristics (T_a = 25°C) < Tr1 and Tr2>

Davamatav	Symbol	Conditions	Values			Unit	
Parameter	Symbol	ool Conditions		Тур.	Max.	Urill	
Input capacitance	C _{iss}	V _{GS} = 0V	-	25	-		
Output capacitance	C _{oss}	V _{DS} = 10V	-	10	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	10	-		
Turn - on delay time	t _{d(on)} *3	$V_{DD} \simeq 10V, V_{GS} = 4.0V$	-	5	-		
Rise time	t _r *3	I _D = 150mA	-	10	-		
Turn - off delay time	t _{d(off)} *3	$R_L = 67\Omega$	-	15	-	ns	
Fall time	t _f *3	$R_G = 10\Omega$	-	10	-		

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

<Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			l lait
		Conditions	Min.	Тур.	Max.	Unit
Forward voltage	V _{SD} *3	V _{GS} = 0V, I _S = 100mA	-	-	1.2	V

^{*1} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*2} Each terminal mounted on a reference footprint.

^{*3} Pulsed

Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

120

100

80

60

40

20

0 50 100 150 200

Junction Temperature : T_j [°C]

Fig.2 Drain Current Derating Curve

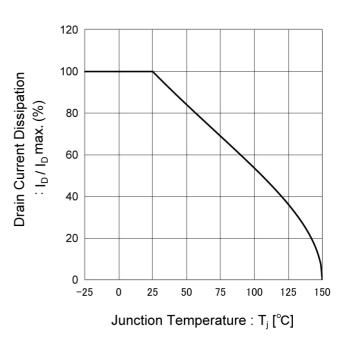


Fig.3 Typical Output Characteristics(I)

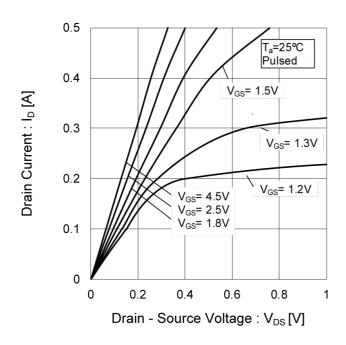
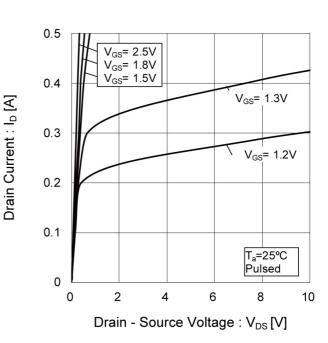


Fig.4 Typical Output Characteristics(II)



• Electrical characteristic curves

Fig.5 Breakdown Voltage vs.
Junction Temperature

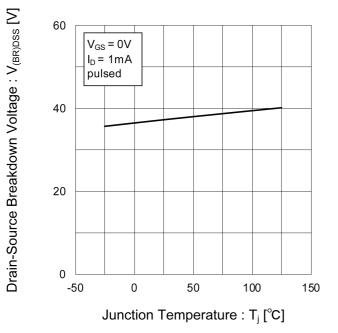


Fig.6 Typical Transfer Characteristics

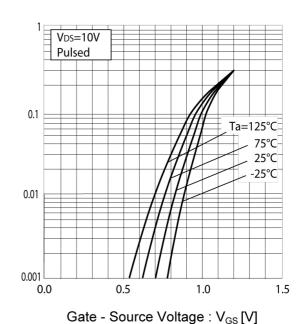


Fig.7 Gate Threshold Voltage vs.
Junction Temperature

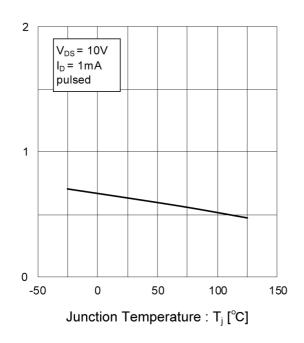
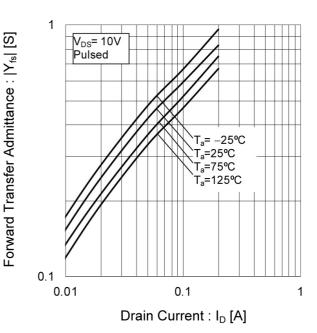


Fig.8 Forward Transfer Admittance vs.
Drain Current



Gate Threshold Voltage: V_{GS(th)} [V]

Drain Current : I_D [A]

• Electrical characteristic curves

Fig.9 Static Drain - Source On - State Resistance vs. Gate Source Voltage

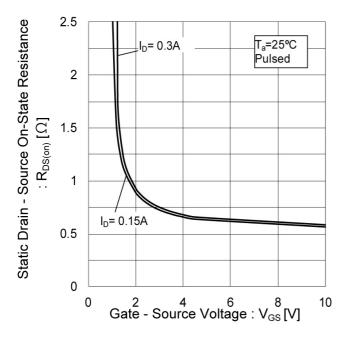


Fig.10 Static Drain - Source On - State
Resistance vs. Junction Temperature

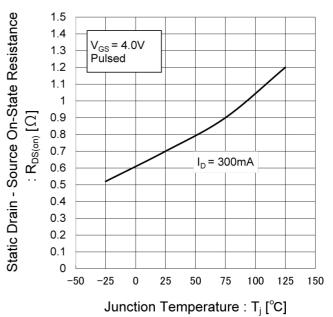
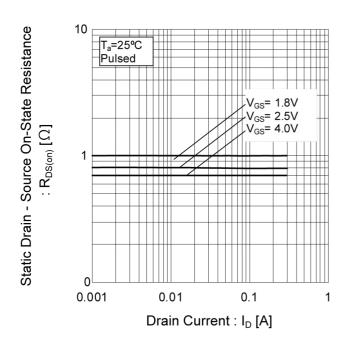


Fig.11 Static Drain - Source On - State
Resistance vs. Drain Current (I)



6/10

• Electrical characteristic curves

Fig.12 Static Drain - Source On - State Resistance vs. Drain Current (II)

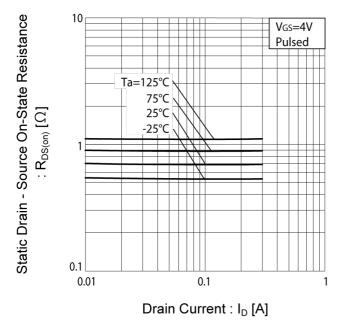


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current (III)

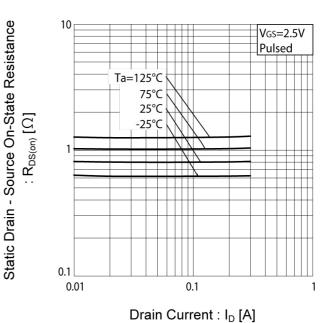
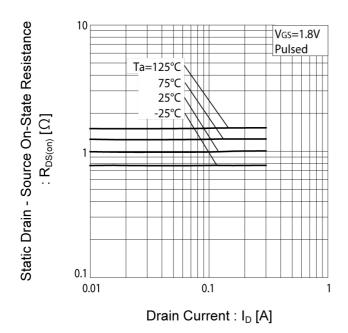


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (IV)





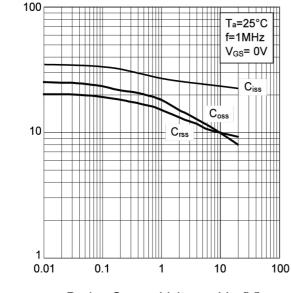
Capacitance : C [pF]

Inverse Diode Forward Current : Is [A]

• Electrical characteristic curves

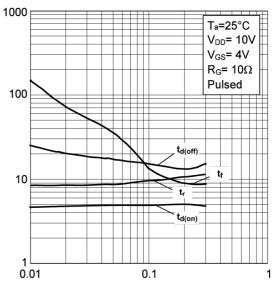
Fig.15 Typical Capacitance vs.

Drain - Source Voltage



Drain - Source Voltage : $V_{DS}[V]$

Fig.16 Switching Characteristics

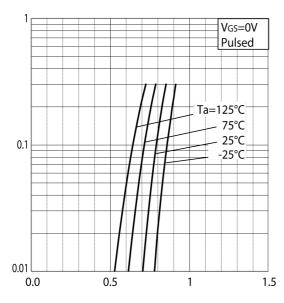


Switching Time : t [ns]

Drain Current : I_D [A]

Fig.17 Source Current vs.

Source Drain Voltage

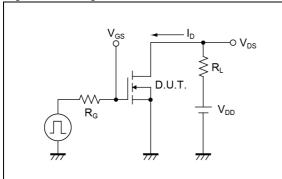


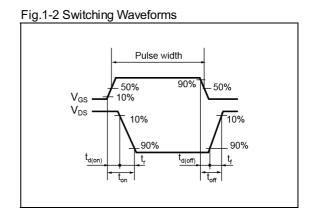
Source - Drain Voltage: V_{SD} [V]

EM6K6

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

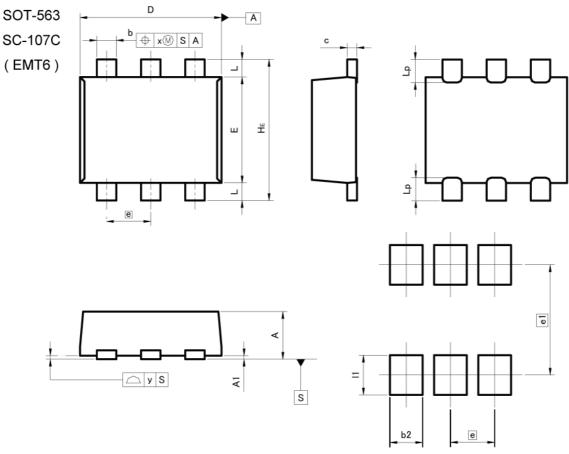




Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

	MILIMETERS			UE6	
DIM	IVITETIVI	ETERS	INCHES		
Diw	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0.000	0.004	
b	0.17	0.27	0.007	0.011	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.059	0.067	
E	1.10	1.30	0.043	0.051	
е	0.	50	0.0	20	
HE	1.50	1.70	0.059	0.067	
L	0.10	0.30	0.004	0.012	
Lp	_	0.35	_	0.014	
х	-	0.10	_	0.004	
У	_	0.10	-	0.004	

DIM	MILIM	ETERS	INCHES		
DIM	MIN MAX		MIN	MAX	
b2	-	0.37	_	0.015	
e1	1.25		0.0	49	
- 11	-	0.45	=	0.018	

Dimension in mm/inches



Notice

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CL ACCTI
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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